COMPLIANT

HALOGEN FREE

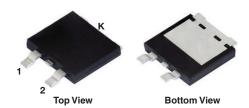


Vishay General Semiconductor

Dual High-Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.36 \text{ V}$ at $I_F = 5 \text{ A}$

eSMP[®] Series SMPD (TO-263AC)





LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 30 A			
V _{RRM}	100 V			
I _{FSM}	320 A			
V_F at $I_F = 30$ A $(T_A = 125 ^{\circ}C)$	0.66 V			
T _J max.	150 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			

FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
 - Automotive ordering code: base P/NHM3
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER Maximum repetitive peak reverse voltage		SYMBOL	V60D100C	UNIT V	
		V _{RRM}	100		
Maximum average forward rectified current (fig. 1)	per device		60	^	
	per diode	I _{F(AV)}	30	A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I _{FSM}	320	А	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.45	-	V	
	$I_F = 15 A$			0.62	-		
	I _F = 30 A			0.75	0.81		
	I _F = 5 A	T _A = 125 °C		0.36	-		
	I _F = 15 A			0.54	-		
	I _F = 30 A			0.66	0.73		
Reverse current at rated V _R per diode	V _R = 70 V	T _A = 25 °C	I _R ⁽²⁾	12	-	μA	
		T _A = 125 °C		11	-	mA	
	V _R = 100 V	T _A = 25 °C		-	1000	μA	
		T _A = 125 °C		27	85	mA	

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width $\leq 5 \text{ ms}$

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60D100C	UNIT	
Typical thermal resistance	per diode	R ₀ JC (3)	1.8	- °C/W	
	per device	R ₀ JC (3)	0.95		
	per device	R _{0JM} (2)	3		
	per device	$R_{\theta JA}^{(1)(2)}$	45		

Notes

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
- (2) Free air mounted on recommended pad size 2 OZ. FR4 PCB; thermal resistance R_{eJA} junction to ambient; thermal resistance R_{eJM} junction
- $^{(3)}$ Thermal resistance $R_{\theta JC}$ junction to K (heatsink). Mounted on infinite heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SMPD (TO-263AC)	V60D100C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel
SMPD (TO-263AC)	V60D100CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel

Note

(1) AEC-Q101 qualified



26 24

22

O

Average Power Loss (W)

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

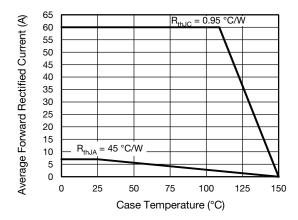


Fig. 1 - Forward Current Derating Curve

D = 0.3

D = 0.1

D = 0.5



Fig. 2 - Forward Power Loss Characteristics Per Diode

Average Forward Current (A)

15

20

25

30

35

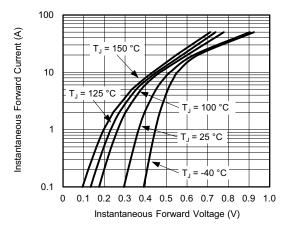


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

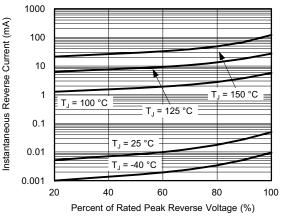


Fig. 4 - Typical Reverse Characteristics Per Diode

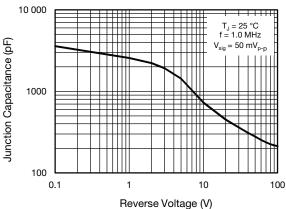


Fig. 5 - Typical Junction Capacitance Per Diode

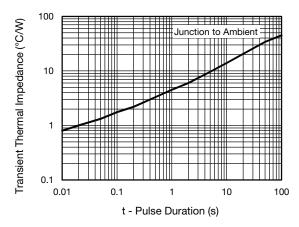


Fig. 6 - Typical Transient Thermal Impedance Per Device





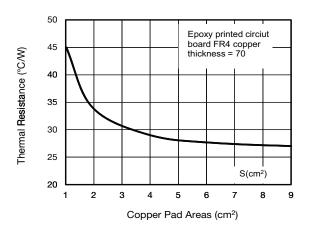
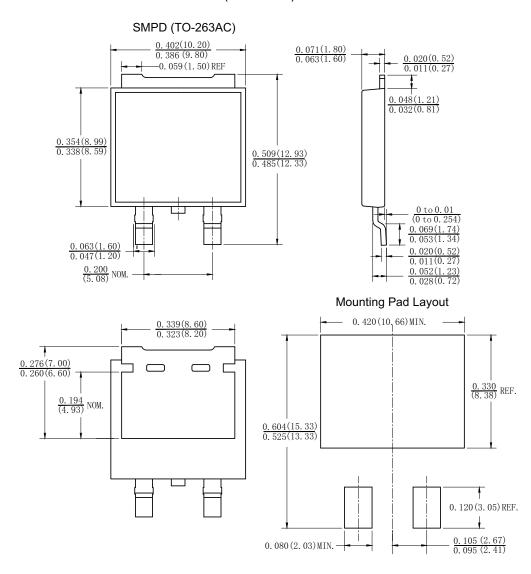


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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